

Resin-Molded Chip, Standard Tantalum J-Lead



FEATURES

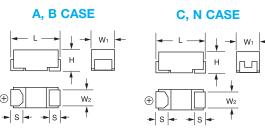
- Compliant to the RoHS2 directive 2011/65/EU
- SMD J-lead





APPLICATIONS

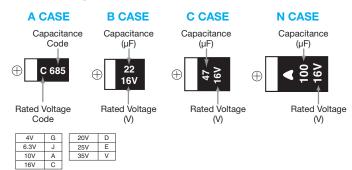
• Low power DC/DC



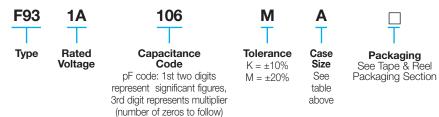
CASE DIMENSIONS: millimeters (inches)

Code	L	W ₁	W ₂	Н	S
Α	3.20 ± 0.20	1.60 ± 0.20	1.20 ± 0.10	1.60 ± 0.20	0.80 ± 0.20
	(0.126 ± 0.008)	,	,	,	, ,
В	3.50 ± 0.20	2.80 ± 0.20	2.20 ± 0.10	1.90 ± 0.20	0.80 ± 0.20
	(0.126 ± 0.008)	(0.110 ± 0.008)	(0.087 ± 0.004)	(0.075 ± 0.008)	(0.031 ± 0.008)
С	6.00 ± 0.20	3.20 ± 0.20	2.20 ± 0.10	2.50 ± 0.20	1.30 ± 0.20
	(0.236 ± 0.008)	(0.126 ± 0.008)	(0.087 ± 0.004)	(0.098 ± 0.008)	(0.051 ± 0.008)
N	7.30 ± 0.20	4.30 ± 0.20	2.40 ± 0.10	2.80 ± 0.20	1.30 ± 0.20
	(0.287 ± 0.008)	(0.169 ± 0.008)	(0.094 ± 0.004)	(0.110 ±0.008)	(0.051 ± 0.008)

MARKING



HOW TO ORDER



TECHNICAL SPECIFICATIONS

Category Temperature Range:	-55 to +125°C
Rated Temperature:	+85°C
Capacitance Tolerance:	±20%, ±10% at 120Hz
Dissipation Factor:	Refer to next page
ESR 100kHz:	Refer to next page
Leakage Current:	After 1 minute's application of rated voltage, leakage current at 20°C
	is not more than 0.01CV or 0.5µA, whichever is greater.
	After 1 minute's application of rated voltage, leakage current at 85°C
	is not more than 0.1CV or 5μA, whichever is greater.
	After 1 minute's application of derated voltage, leakage current at 125°C
	is not more than 0.125CV or 6.3µA, whichever is greater.
Capacitance Change By Temperature	+15% Max. at +125°C
	+10% Max. at +85°C
	-10% Max. at -55°C





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CAPACITANCE AND RATED VOLTAGE RANGE (LETTER DENOTES CASE SIZE)

Capacitance		Rated Voltage								
μF	Code	4V (0G)	6.3V (0J)	10V (1A)	16V (1C)	20V (1D)	25V (1E)	35V (1V)		
0.68	684							А		
1	105				Α		А	А		
1.5	155				А		А	А		
2.2	225				А	А	А	A/B		
3.3	335				А	А	А	В		
4.7	475			А	Α	A/B	A/B	B/C		
6.8	685			А	А	A/B		С		
10	106		А	А	A/B	A/B	B/C	С		
15	156		А	А	A/B	С	С	N		
22	226	А	А	A/B	A/B/C	B/C	C/N	N		
33	336	А	А	A/B	B/C	C/N	N			
47	476	А	A/B	A/B/C	B*/C/N	C/N	N			
68	686	А	A/B	B/C	C/N	N*				
100	107	A/B	A/B/C	B/C/N	C/N					
150	157	В	B/C	C/N	N					
220	227	A*/B/C	B/C/N	N	N					
330	337	С	N	N						
470	447	N	N							
680	687	N								

Available Ratings

*Codes under development – subject to change

Please contact to your local AVX sales office when these series are being designed in your application.



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RATINGS & PART NUMBER REFERENCE

AVX Part No.	Case Size	Capacitance (µF)	Rated Voltage (V)	DCL (μA)	DF (%) @ 120Hz	ESR (Ω) @ 100kHz	*1 ∆C/C (%)
			4 Vol	t			
F930G226MAA	Α	22	4	0.9	6	2.5	*
F930G336MAA	A	33	4	1.3	8	2.5	*
F930G476MAA	A	47	4	1.9	18	2.5	*
F930G686MAA	A		4				*
		68		2.7	24	2.5	*
F930G107MAA	Α	100	4	4.0	30	2.0	*
F930G107MBA	В	100	4	4.0	14	0.9	
F930G157MBA	В	150	4	6.0	16	0.7	*
F930G227MBA	В	220	4	8.8	18	0.7	*
F930G227MCC	С	220	4	8.8	12	0.7	*
F930G337MCC	С	330	4	13.2	14	0.7	*
F930G477MNC	N	470	4	18.8	16	0.3	*
F930G687MNC	N	680	4	27.2	18	0.3	*
1 300 000 1 1 1 1 1 0	11	000	6.3 Vo		10	0.0	
F930J106MAA	Α	10	6.3	0.6	6	3.0	*
							*
F930J156MAA	Α	15	6.3	0.9	6	2.9	*
F930J226MAA	A	22	6.3	1.4	8	2.5	*
F930J336MAA	Α	33	6.3	2.1	8	2.5	
F930J476MAA	Α	47	6.3	3.0	18	2.5	*
F930J476MBA	В	47	6.3	3.0	6	1.0	*
F930J686MAA	Α	68	6.3	4.3	20	2.0	*
F930J686MBA	В	68	6.3	4.3	8	1.0	*
F930J107MAA	Ā	100	6.3	6.3	35	2.0	±15
F930J107MBA	В	100	6.3	6.3	14	0.9	*
	-						*
F930J107MCC	C	100	6.3	6.3	8	0.7	*
F930J157MBA	В	150	6.3	9.5	18	0.9	*
F930J157MCC	C	150	6.3	9.5	12	0.7	
F930J227MBA	В	220	6.3	13.9	30	1.2	±15
F930J227MCC	С	220	6.3	13.9	14	0.7	*
F930J227MNC	N	220	6.3	13.9	10	0.5	*
F930J337MNC	N	330	6.3	20.8	14	0.5	*
F930J477MNC	N	470	6.3	29.6	16	0.3	*
1 0000 11 1111110		110	10 Vo		10	0.0	
F931A475MAA	Α	4.7	10	0.5	6	4.0	*
F931A685MAA	A	6.8	10	0.7	6	3.5	*
F931A106MAA	A	10	10	1.0	6		*
						3.0	*
F931A156MAA	Α	15	10	1.5	8	2.9	*
F931A226MAA	Α	22	10	2.2	12	2.5	
F931A226MBA	В	22	10	2.2	6	1.9	*
F931A336MAA	A	33	10	3.3	18	2.5	*
F931A336MBA	В	33	10	3.3	8	1.4	*
F931A476MAA	Α	47	10	4.7	40	2.0	±15
F931A476MBA	В	47	10	4.7	8	1.0	*
F931A476MCC	C	47	10	4.7	6	0.9	*
F931A686MBA	В	68	10	6.8	12	0.9	±15
	C		10				±10
F931A686MCC		68		6.8	8	0.8	
F931A107MBA	В	100	10	10.0	18	1.2	±15
F931A107MCC	C	100	10	10.0	10	0.7	*
F931A107MNC	N	100	10	10.0	8	0.6	*
F931A157MCC	С	150	10	15.0	14	0.7	*
F931A157MNC	N	150	10	15.0	10	0.6	*
F931A227MNC	N	220	10	22.0	12	0.5	*
F931A337MNC	N	330	10	33.0	18	0.5	*
. 5517 (507 (VIII 40			16 Vo		0	0.0	
F931C105MAA	Α	1	16	0.5	4	7.5	*
F931C155MAA	A	1.5	16	0.5	4	6.0	*
							*
F931C225MAA	A	2.2	16	0.5	4	5.0	*
F931C335MAA	Α	3.3	16	0.5	4	4.5	
F931C475MAA	Α	4.7	16	0.8	6	4.0	*
F931C685MAA	Α	6.8	16	1.1	6	3.5	*

AVX	Case	Capacitance	Rated	DCL	DF	ESR	*1
Part No.	Size	(μF)	Voltage (V)	(μΑ)	(%) @ 120Hz	(Ω) @ 100kHz	∆C/C (%)
F931C106MAA	Α	10	16	1.6	6	3.0	*
F931C106MBA	В	10	16	1.6	6	2.0	*
F931C156MAA	Α	15	16	2.4	10	3.0	*
F931C156MBA	В	15	16	2.4	6	2.0	*
F931C226MAA	A	22	16	3.5	15	3.0	±15 *
F931C226MBA	В	22	16	3.5	8	1.9	*
F931C226MCC F931C336MBA	B	33	16 16	3.5 5.3	6 8	1.1 1.9	*
F931C336MCC	C	33	16	5.3	6	1.1	*
F931C476MCC	C	47	16	7.5	8	0.9	*
F931C476MNC	Ň	47	16	7.5	6	0.7	*
F931C686MCC	C	68	16	10.9	10	0.8	±10
F931C686MNC	Ň	68	16	10.9	6	0.6	*
F931C107MCC	C	100	16	16.0	15	0.7	±10
F931C107MNC	N	100	16	16.0	10	0.6	*
F931C157MNC	N	150	16	24.0	15	0.6	*
F931C227MNC	N	220	16	35.2	25	0.7	±10
50010005111			20 Vo				*
F931D225MAA	Α	2.2	20	0.5	4	5.0	*
F931D335MAA	Α	3.3	20	0.7	4	4.5	*
F931D475MAA F931D475MBA	A B	4.7	20	0.9	6	3.0	*
F931D685MAA	A	6.8	20	1.4	6	3.5	*
F931D685MBA	В	6.8	20	1.4	6	2.5	*
F931D106MAA	A	10	20	2.0	8	3.5	*
F931D106MBA	В	10	20	2.0	6	2.1	*
F931D156MCC	C	15	20	3.0	6	1.2	*
F931D226MBA	В	22	20	4.4	8	1.9	*
F931D226MCC	C	22	20	4.4	8	1.1	*
F931D336MCC	С	33	20	6.6	8	1.1	*
F931D336MNC	N	33	20	6.6	6	0.7	*
F931D476MCC	С	47	20	9.4	10	1.1	*
F931D476MNC	N	47	20	9.4	8	0.7	*
E004E40ENAAA	Ι Δ	_	25 Vo		4	7.5	*
F931E105MAA	Α	11	25	0.5	4	7.5	*
F931E155MAA F931E225MAA	Α	1.5	25 25	0.5	6	6.7	*
F931E335MAA	A	3.3	25	0.6	6	6.3	*
F931E475MAA	A	4.7	25	1.2	8	4.0	*
F931E475MBA	В	4.7	25	1.2	6	2.8	*
F931E106MBA	В	10	25	2.5	12	1.9	*
F931E106MCC	C	10	25	2.5	6	1.5	*
F931E156MCC	Č	15	25	3.8	8	1.2	*
F931E226MCC	Č	22	25	5.5	8	1.1	*
F931E226MNC	N	22	25	5.5	6	0.7	*
F931E336MNC	N	33	25	8.3	8	0.7	*
F931E476MNC	N	47	25	11.8	8	0.7	*
F004\/C04\AAA	ΙΛ	0.60	35 Vo		1	7.0	*
F931V684MAA F931V105MAA	A	0.68	35 35	0.5 0.5	4	7.6 7.5	*
F931V155MAA	A	1.5	35	0.5	6	7.5	*
F931V225MAA	A	2.2	35	0.8	6	7.0	*
F931V225MBA	В	2.2	35	0.8	4	3.8	*
F931V335MBA	В	3.3	35	1.2	4	3.5	*
F931V475MBA	В	4.7	35	1.6	8	3.1	*
F931V475MCC	C	4.7	35	1.6	6	1.8	*
F931V685MCC	Č	6.8	35	2.4	6	1.8	*
F931V106MCC	Č	10	35	3.5	6	1.6	*
F931V156MNC	N	15	35	5.3	6	0.7	*
F931V226MNC	N	22	35	7.7	8	0.7	*
L							

^{*1: ∆}C/C Marked "*"

Item	All Case (%)
Damp Heat	±10
Temperature cycles	±5
Resistance soldering heat	±5
Surge	±5
Endurance	±10



 $^{^{\}star}$ In case of capacitance tolerance \pm 10% type, "K" will be put at 9th digit of type numbering system



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QUALIFICATION TABLE

TEST	F93 series (Temperature range -55°C to +125°C)
1231	Condition
Damp Heat	At 40°C, 90 to 95% R.H., 500 hours (No voltage applied) Capacitance Change Refer to page 20 (*1)
(Steady State)	Dissipation Factor
(Oteady Otate)	Leakage Current
	-55°C / +125°C, 30 minutes each, 5 cycles
T	Capacitance Change
Temperature Cycles	Dissipation Factor Initial specified value or less
	Leakage Current Initial specified value or less
	10 seconds reflow at 260°C, 5 seconds immersion at 260°C.
Resistance to	Capacitance Change Refer to page 20 (*1)
Soldering Heat	Dissipation Factor Initial specified value or less
	Leakage Current Initial specified value or less
	After application of surge voltage in series with a 33Ω resistor at the rate of 30 seconds ON, 30 seconds OFF,
	for 1000 successive test cycles at 85°C, capacitors shall meet the characteristic requirements in the table above.
Surge	Capacitance Change Refer to page 20 (*1)
	Dissipation Factor Initial specified value or less
	Leakage Current Initial specified value or less
	After 2000 hours' application of rated voltage in series with a 3Ω resistor at 85°C, or derated voltage in series
	with a 3Ω resistor at 125°C, capacitors shall meet the characteristic requirements in the table above.
Endurance	Capacitance Change Refer to page 20 (*1)
	Dissipation Factor
	Leakage Current
Shear Test	After applying the pressure load of 5N for 10±1 seconds horizontally to the center of capacitor side body which has no electrode and has been soldered beforehand on a substrate, there shall be found neither 5N (0.51kg·1)
onear rest	exfoliation nor its sign at the terminal electrode.
	Kanning a connection symfole many rated on a sylbatrate consider daying and sympositing the sylbatrate of
	both of the opposite bottom points 45mm apart from the center of capacitor, the pressure strength is
Terminal Strength	applied with a specified jig at the center of substrate so that the substrate may bend by 1mm as
	illustrated. Then, there shall be found no remarkable abnormality on the capacitor terminals.
F-llow Data	1% per 1000 hours at 85°C, VR with 0.1Ω/V series impedance.
Failure Rate	60% confidence level.

We can supply the type of compliance to AEC-Q200. Please contact to your local AVX sales office when these series are being designed in your application.

